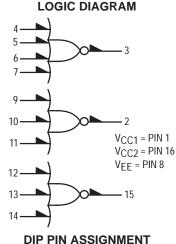
Triple 4-3-3-Input Bus Driver

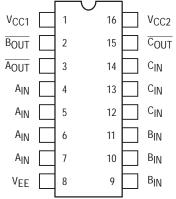
The MC10H123 is a triple 4–3–3–Input Bus Driver.

The MC10H123 consists of three NOR gates designed for bus driving applications on card or between cards. Output low logic levels are specified with $V_{OL} = -2.1$ Vdc so that the bus may be terminated to -2.0 Vdc. The gate output, when low, appears as a high impedance to the bus, because the output emitter-followers of the MC10H123 are "turned-off." This eliminates discontinuities in the characteristic impedance of the bus.

The V_{OH} level is specified when driving a 25–ohm load terminated to -2.0 Vdc, the equivalent of a 50-ohm bus terminated at both ends. Although 25 ohms is the lowest characteristic impedance that can be driven by the MC10H123, higher impedance values may be used with this part. A typical 50-ohm bus is shown in Figure 1.

- Propagation Delay, 1.5 ns Typical
- Improved Noise Margin 150 mV (Over Operating Voltage and Temperature Range)
- Voltage Compensated
- MECL 10K-Compatible





Pin assignment is for Dual-in-Line Package. For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).



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MARKING DIAGRAMS



CDIP-16 **L SUFFIX CASE 620**





PDIP-16 **P SUFFIX CASE 648**





PLCC-20 **FN SUFFIX CASE 775**



= Assembly Location

WL = Wafer Lot YY = Year

WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping		
MC10H123L	CDIP-16	25 Units/Rail		
MC10H123P	PDIP-16	25 Units/Rail		
MC10H123FN	PLCC-20	46 Units/Rail		

MAXIMUM RATINGS

Symbol	Characteristic	Rating	Unit
VEE	Power Supply (V _{CC} = 0)	-8.0 to 0	Vdc
VI	Input Voltage (V _{CC} = 0)	0 to VEE	Vdc
l _{out}	Output Current — Continuous — Surge	50 100	mA
TA	Operating Temperature Range	0 to +75	°C
T _{stg}	Storage Temperature Range — Plastic — Ceramic	−55 to +150 −55 to +165	°C

ELECTRICAL CHARACTERISTICS (V_{EE} = -5.2 V ±5%) (See Note 1.)

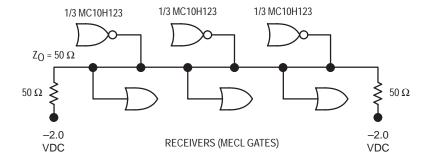
		0 °		25°		75 °		
Symbol	Characteristic	Min	Max	Min	Max	Min	Max	Unit
ΙE	Power Supply Current	_	60	_	56		60	mA
linH	Input Current High	_	495	_	310	_	310	μΑ
l _{inL}	Input Current Low	0.5	_	0.5	_	0.3	_	μΑ
VOH	High Output Voltage	-1.02	-0.84	-0.98	-0.81	-0.92	-0.735	Vdc
VOL	Low Output Voltage	-2.1	-2.03	-2.1	-2.03	-2.1	-2.03	Vdc
VIH	High Input Voltage	-1.17	-0.84	-1.13	-0.81	-1.07	-0.735	Vdc
VIL	Low Input Voltage	-1.95	-1.48	-1.95	-1.48	-1.95	-1.45	Vdc

AC PARAMETERS

	^t pd	Propagation Delay	0.7	1.5	0.7	1.6	0.7	1.7	ns
	t _r	Rise Time	0.7	1.6	0.7	1.7	0.7	1.8	ns
Γ	t _f	Fall Time	0.7	1.6	0.7	1.7	0.7	1.8	ns

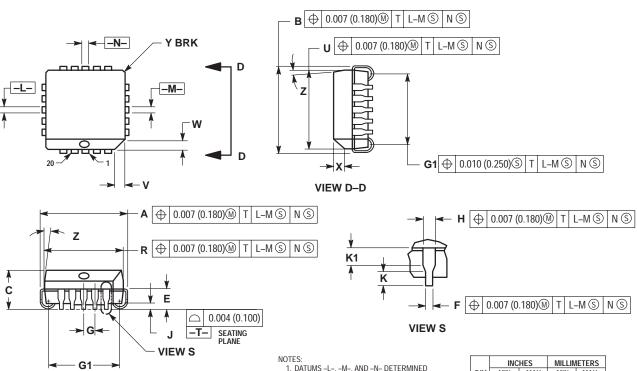
^{1.} Each MECL 10H series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained. Outputs are terminated through a 50–ohm resistor to –2.1 volts.

FIGURE 1 — 50-OHM BUS DRIVER (25-OHM LOAD)



PACKAGE DIMENSIONS

PLCC-20 **FN SUFFIX** PLASTIC PLCC PACKAGE CASE 775-02 **ISSUE C**



- WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.
- 2. DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.

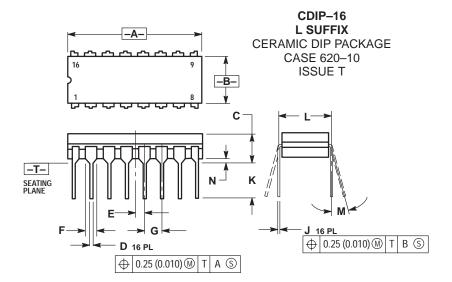
 3. DIMENSIONS R AND U DO NOT INCLUDE MOLD.
- FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE. 4. DIMENSIONING AND TOLERANCING PER ANSI
- 4. DIMENSIONING AND TOLERANCING FER ANSI Y14.5M, 1982. 5. CONTROLLING DIMENSION: INCH. 6. THE PACKAGE TOP MAY BE SMALLER THAN THE

⊕ 0.010 (0.250)⑤ T L-M ⑤ N ⑥

- PACKAGE BOTTOM BY UP TO 0.012 (0.300).
 DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP
- INCLUDING ANY MISMAICH BE I WEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

 7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.385	0.395	9.78	10.03	
В	0.385	0.395	9.78	10.03	
С	0.165	0.180	4.20	4.57	
Ε	0.090	0.110	2.29	2.79	
F	0.013	0.019	0.33	0.48	
G	0.050	BSC	1.27	BSC	
Н	0.026	0.032	0.66	0.81	
J	0.020		0.51		
K	0.025		0.64		
R	0.350	0.356	8.89	9.04	
U	0.350	0.356	8.89	9.04	
٧	0.042	0.048	1.07	1.21	
W	0.042	0.048	1.07	1.21	
Х	0.042	0.056	1.07	1.42	
Υ		0.020		0.50	
Z	2°	10°	2°	10 °	
G1	0.310	0.330	7.88	8.38	
K1	0.040		1.02		

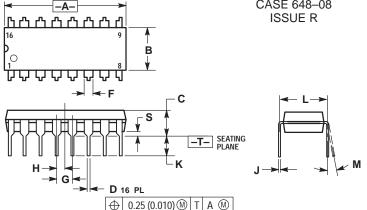


NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEAD WHEN
- FORMED PARALLEL.
 DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC

	INC	HES	MILLIMETERS		
DIM	MIN MAX		MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015 0.020		0.39 0.50		
Ε	0.050 BSC		1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100	BSC	2.54 BSC		
Н	0.008	0.015	0.21	0.38	
K	0.125	0.170	3.18	4.31	
L	0.300	0.300 BSC		BSC	
M	0°	15°	0 °	15°	
N	0.020	0.040	0.51	1.01	





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- DIMENSION B DOES NOT INCLUDE MOLD FLASH.
- ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIMETERS				
DIM	MIN	MAX	MIN	MAX			
Α	0.740	0.770	18.80	19.55			
В	0.250	0.270	6.35	6.85			
С	0.145	0.175	3.69	4.44			
D	0.015	0.021	0.39	0.53			
F	0.040	0.70	1.02	1.77			
G	0.100 BSC		2.54 BSC				
Н	0.050	BSC	1.27 BSC				
J	0.008	0.015	0.21	0.38			
K	0.110	0.130	2.80	3.30			
L	0.295	0.305	7.50	7.74			
M	0°	10°	0 °	10 °			
S	0.020	0.040	0.51	1.01			

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